Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass **Overall Length:** 0.450 inches **Overall Height:** 1.000 inches **Mounting Facility Quantity:** 1 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 320.0 working peak reverse voltage **Current Rating Per Characteristic:** 25.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector Maximum Operating Tempurature Per Measurement Point: 190.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** Yes - demil/mli Fiig: A110a0